# Phonon-assisted luminescence in hBN monolayer from first principles



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### Introduction

We compute the photoluminescence of a monolayer of hexagonal Boron Nitride from first principles. Our new approach allows to have both direct peaks and satellites coming from phonon-assisted transitions in the same spectra. We combine Density Functional Theory (DFT), Density Functional Perturbation Theory (DFPT) and Many-Body Perturbation Theory (MBPT) to obtain the excitonphonon coupling matrix elements ab initio. Then we make use of the van Roosbroeck – Shockley relation, which is a steady-state approximation, to compute the photoluminescence from the dielectric function. Finally we compare our result with three experimental measurements [1-3] and rule out the possibility of phonon satellites being visible in the spectrum of monolayer hBN.



#### Benchmark



## **Exciton-phonon coupling**

After computing the electron-phonon matrix elements in DFPT, we rotate the matrix elements for chosen bands to obtain the holephonon and electron-phonon matrix elements in the excitonic basis Their difference defines the **exciton-phonon coupling** matrix elements :

$$\mathcal{G}_{\beta\alpha,\mu}(\mathbf{Q},\mathbf{q}) = \sum_{\substack{v,v'\\c,c',\mathbf{k}}} A^{v,c,\mathbf{k}}_{\alpha,\mathbf{Q}} \left[ g_{vv',\mu}(\mathbf{k}-\mathbf{Q},\mathbf{q})\delta_{c,c'} \right] A^{v',c',\mathbf{k}^*}_{\beta,\mathbf{Q}+\mathbf{q}} - \sum_{\substack{v,v'\\c,c',\mathbf{k}}} A^{v,c,\mathbf{k}}_{\alpha,\mathbf{Q}} \left[ g^*_{c'c,\mu}(\mathbf{k}+\mathbf{q},\mathbf{q})\delta_{v,v'} \right] A^{v',c',\mathbf{k}+\mathbf{q}^*}_{\beta,\mathbf{Q}+\mathbf{q}}$$



#### Luminescence compared to experiments



• Very intense direct peak

• Almost invisible LO/TO replica • Indirect exciton not visible due

Magnitude of the coupling (in eV) between the lowest-lying exciton at  $\Gamma$  and all phonon modes over the Brillouin Zone

Photoluminescence of **monolayer hBN** a) This work (shifted to match experiments) b) Ref [1] on Graphite c) Ref [2] on SiO, d) Ref [3] on Graphite

## **Direct/indirect energy** difference



#### **Exciton dispersion**



Exciton dispersion of monolayer hBN. Depending on the level of theory, the minimum exciton can be at K or at  $\Gamma$ .

The lowest exciton at K comes from the nearly-free electronic states at Γ. It is not contributing to luminescence and is lifted in energy when a substrate is present.



Effect of the energy difference between direct exciton and indirect exciton at K. Boltzmann occupation is displayed in green.

- The equilibrium exciton dispersion gives only the direct peak
- In the case when the substrate brings them to the same energy, only the direct peak is visible
- Only when K is lower, both direct and satellite peaks are visible

## **Conclusion and perspectives**

• Ab initio exciton-phonon coupling and phonon-assisted luminescence with quantitative comparison of direct peaks and replicas intensities • In monolayer hBN, spectrum is dominated by direct peak and phonon-assisted satellites are not visible

• Would need the indirect exciton to be the lowest to produce a peak in the spectrum



Study of a system with direct and indirect excitons very close in energy (Bernal BN) Work out numerical issues and release the implementation

[1] Elias, Christine, et al. "Direct band-gap crossover in epitaxial monolayer boron nitride." Nature communications 10.1 (2019) [2] Rousseau, Adrien, et al. "Monolayer Boron Nitride: Hyperspectral Imaging in the Deep Ultraviolet." Nano Letters 21.23 (2021) [3] Wang, Ping, et al. "Scalable Synthesis of Monolayer Hexagonal Boron Nitride on Graphene with Giant Bandgap Renormalization." Advanced Materials 34.21 (2022). [4] Schué, Léonard, et al. "Bright luminescence from indirect and strongly bound excitons in h-BN." Physical review letters 122.6 (2019) [5] Chen, Hsiao-Yi, D. Sangalli, M. Bernardi. "Exciton-phonon interaction and relaxation times from first principles." Physical Review Letters 125.10 (2020)



